National Semiconductor

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DS36C280
Slew Rate Controlled CMOS EIA-RS-485 Transceiver

General Description

The DS36C280 is a low power differential bus/line transceiver designed to meet the requirements of RS-485 Standard for multipoint data transmission. In addition, it is compatible with TIA/EIA-422-B.

The slew rate control feature allows the user to set the driver rise and fall times by using an external resistor. Controlled edge rates can reduce switching EMI.

The CMOS design offers significant power savings over its bipolar and ALS counterparts without sacrificing ruggedness against ESD damage. The device is ideal for use in battery powered or power conscious applications. I_{CC} is specified at 500 µA maximum.

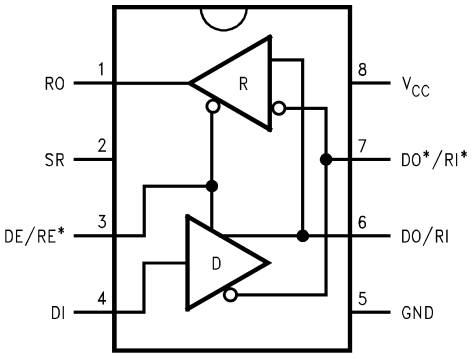
The driver and receiver outputs feature TRI-STATE® capability. The driver outputs operate over the entire common mode range of −7V to +12V. Bus contention or fault situations are handled by a thermal shutdown circuit, which forces the driver outputs into the high impedance state.

The receiver incorporates a fail safe circuit which guarantees a high output state when the inputs are left open (Note 1) .

Features

- 100% RS-485 compliant
  — Guaranteed RS-485 device interoperation
- Low power CMOS design: I_{CC} 500 µA max
- Adjustable slew rate control
  — Minimizes EMI affects
- Built-in power up/down glitch-free circuitry
  — Permits live transceiver insertion/displacement
- SOIC packages
- Industrial temperature range: −40˚C to +85˚C
- On-board thermal shutdown circuitry
  — Prevents damage to the device in the event of excessive power dissipation
- Wide common mode range: −7V to +12V
- Receiver open input fail-safe (Note 1)
- ¼ unit load (DS36C280): ≥128 nodes
- ½ unit load (DS36C280T): ≥64 nodes
- ESD (human body model): ≥2 kV

Connection and Logic Diagram



01205201

Order Number DS36C280M, DS36C280TM
See NS Package Number M08A

Truth Table

DRIVER SECTION			
DE/RE*	**DI**	**DO/RI**	**DO*/RI***
H	H	H	L
H	L	L	H
L	X	Z	Z

RECEIVER SECTION		
DE/RE*	**RI-RI***	**RO**
L	≥+0.2V	H
L	≤−0.2V	L
H	X	Z
L	OPEN (Note 1)	H

Note 1: Non-terminated, Open Inputs only

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Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC})	+12V
Input Voltage (DE/RE*, & DI)	−0.5V to (V_{CC} +0.5V)
Common Mode (V_{CM}) Driver Output/Receiver Input	±15V
Input Voltage (DO/RI, DO*/RI*)	±14V
Receiver Output Voltage	−0.5V to (V_{CC} +0.5V)
Maximum Package Power Dissipation @ +25˚C M Package 1190 mV, derate	9.5 mW/˚C above +25˚C
Storage Temperature Range	−65˚C to +150˚C
Lead Temperature (Soldering 4 sec.)	+260˚C

Recommended Operating Conditions

	Min	Typ	Max	Units
Supply Voltage (V_{CC})	+4.75	+5.0	+5.25	V
Bus Voltage	−7		+12	V
Operating Free Air Temperature (T_A)				
DS36C280T	−40	+25	+85	˚C
DS36C280	0	+25	+70	˚C

Electrical Characteristics (Notes 3, 4)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions		Reference		Min	Typ	Max	Units
DIFFERENTIAL DRIVER CHARACTERISTICS									
V_{OD1}	Differential Output Voltage	I_O = 0 mA (No Load)		(422) (485)		1.5		5.0	V
V_{OD0}	Output Voltage	I_O = 0 mA (Output to GND)				0		5.0	V
V_{OD0*}	Output Voltage					0		5.0	V
V_{OD2}	Differential Output Voltage (Termination Load)	R_L = 50Ω		(422)	*Figure 1*	2.0	2.8		V
		R_L = 27Ω		(485)		1.5	2.3	5.0	V
ΔV_{OD2}	Balance of V_{OD2} $\lvert V_{OD2} - V_{OD2*}\rvert$	R_L = 27Ω or 50Ω		(Note 5) (422, 485)		−0.2	0.1	+0.2	V
V_{OD3}	Differential Output Voltage (Full Load)	R1 = 54Ω, R2 = 375Ω		*Figure 2*		1.5	2.0	5.0	V
		V_{TEST} = −7V to +12V							
V_{OC}	Driver Common Mode Output Voltage	R_L = 27Ω		(485)	*Figure 1*	0		3.0	V
		R_L = 50Ω		(422)		0		3.0	V
ΔV_{OC}	Balance of V_{OC} $\lvert V_{OC} - V_{OC*}\rvert$	R_L = 27Ω or R_L = 50Ω		(Note 5) (422, 485)		−0.2		+0.2	V
I_{OSD}	Driver Output Short-Circuit Current	V_O = +12V		(485) *Figure 4*			200	+250	mA
		V_O = −7V		(485)			−190	−250	mA
RECEIVER CHARACTERISTICS									
V_{TH}	Differential Input High Threshold Voltage	$V_O = V_{OH}$, I_O = −0.4 mA −7V ≤ V_{CM} ≤ +12V		(Note 6) (422, 485)			+0.035	+0.2	V
V_{TL}	Differential Input Low Threshold Voltage	$V_O = V_{OL}$, I_O = 0.4 mA −7V ≤ V_{CM} ≤ +12V				−0.2	−0.035		V
V_{HST}	Hysteresis	V_{CM} = 0V					70		mV
R_{IN}	Input Resistance	−7V ≤ V_{CM} ≤ +12V		DS36C280T		24	68		kΩ
R_{IN}	Input Resistance	−7V ≤ V_{CM} ≤ +12V		DS36C280		48	68		kΩ
I_{IN}	Line Input Current (Note 8)	Other Input = 0V DE = V_{IL}, RE* = V_{IL} V_{CC} = 4.75 to 5.25 or 0V	DS36C280	V_{IN} = +12V		0	0.19	0.25	mA
				V_{IN} = −7V		0	−0.1	−0.2	mA
			DS36C280T	V_{IN} = +12V		0	0.19	0.5	mA
				V_{IN} = −7V		0	−0.1	−0.4	mA
I_{ING}	Line Input Current Glitch (Note 8)	Other Input = 0V DE = V_{IL}, RE* = V_{IL} V_{CC} = +3.0V or 0V T_A = 25˚C	DS36C280	V_{IN} = +12V		0	0.19	0.25	mA
				V_{IN} = −7V		0	−0.1	−0.2	mA
			DS36C280T	V_{IN} = +12V		0	0.19	0.5	mA
				V_{IN} = −7V		0	−0.1	−0.4	mA
I_B	Input Balance Test	RS = 500Ω		(422) (Note 10)				±400	mV

Electrical Characteristics (Notes 3, 4) (Continued)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions		Reference	Min	Typ	Max	Units
RECEIVER CHARACTERISTICS								
V_{OH}	High Level Output Voltage	I_{OH} = −4 mA, V_{ID} = +0.2V		RO *Figure 11*	3.5	4.6		V
V_{OL}	Low Level Output Voltage	I_{OL} = +4 mA, V_{ID} = −0.2V				0.3	0.5	V
I_{OSR}	Short Circuit Current	V_O = GND		RO	7	35	85	mA
I_{OZR}	TRI-STATE Leakage Current	V_O = 0.4V to 2.4V					±1	µA
DEVICE CHARACTERISTICS								
V_{IH}	High Level Input Voltage			DE/RE*, DI	2.0		V_{CC}	V
V_{IL}	Low Level Input Voltage				GND		0.8	V
I_{IH}	High Level Input Current	V_{IH} = V_{CC}					2	µA
I_{IL}	Low Level Input Current	V_{CC} = 5.0V	V_{IL} = 0V				−2	µA
		V_{CC} = +3.0V					−2	µA
		SR = 0V		SR			−1	mA
I_{CCR}	Power Supply Current (No Load)	Driver OFF, Receiver ON		V_{CC}		200	500	µA
I_{CCD}		Driver ON, Receiver OFF				200	500	µA

Switching Characteristics (Notes 4, 9, 11)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions	Reference	Min	Typ	Max	Units
DRIVER CHARACTERISTICS							
t_{PHLD}	Differential Propagation Delay High to Low	R_L = 54Ω, C_L = 100 pF	*Figures 5, 6*	10	399	1000	ns
t_{PLHD}	Differential Propagation Delay Low to High			10	400	1000	ns
t_{SKD}	Differential Skew $\lvert t_{PHLD} - t_{PLHD} \rvert$			0	1	10	ns
t_r	Rise Time	SR = Open			2870		ns
t_f	Fall Time				3070		ns
t_r	Rise Time	SR = 100 kΩ			1590		ns
t_f	Fall Time				1640		ns
t_r	Rise Time	SR = Short		100	337	1000	ns
t_f	Fall Time			100	348	1000	ns
t_{PHZ}	Disable Time High to Z	C_L = 15 pF	*Figures 7, 8*		1100	2000	ns
t_{PLZ}	Disable Time Low to Z		*Figures 9, 10*		500	800	ns
t_{PZH}	Enable Time Z to High	C_L = 100 pF	*Figures 7, 8*		300	500	ns
t_{PZL}	Enable Time Z to Low		*Figures 9, 10*		300	500	ns
RECEIVER CHARACTERISTICS							
t_{PHL}	Propagation Delay High to Low	C_L = 15 pF	*Figures 12, 13*	30	210	400	ns
t_{PLH}	Propagation Delay Low to High			30	190	400	ns
t_{SK}	Skew, $\lvert t_{PHL} - t_{PLH} \rvert$			0	20	50	ns
t_{PLZ}	Output Disable Time	C_L = 15 pF	*Figures 14, 15, 16*		50	150	ns
t_{PHZ}					55	150	ns
t_{PZL}	Output Enable Time				40	150	ns
t_{PZH}					45	150	ns

Note 2: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" specifies conditions of device operation.

Switching Characteristics (Notes 4, 9, 11) (Continued)

Note 3: Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except V_{OD1} and V_{OD2}.

Note 4: All typicals are given for: V_{CC} = +5.0V, T_A = + 25˚C.

Note 5: Delta $|V_{OD2}|$ and Delta $|V_{OC}|$ are changes in magnitude of V_{OD2} and V_{OC}, respectively, that occur when input changes state.

Note 6: Threshold parameter limits specified as an algebraic value rather than by magnitude.

Note 7: Hysteresis defined as $V_{HST} = V_{TH} - V_{TL}$.

Note 8: I_{IN} includes the receiver input current and driver TRI-STATE leakage current.

Note 9: C_L includes probe and jig capacitance.

Note 10: For complete details of test, see RS-485.

Note 11: SR = GND for all Switching Characteristics unless otherwise specified.

Parameter Measurement Information

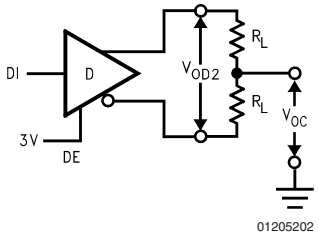


FIGURE 1. Driver V_{OD2} and V_{OC}

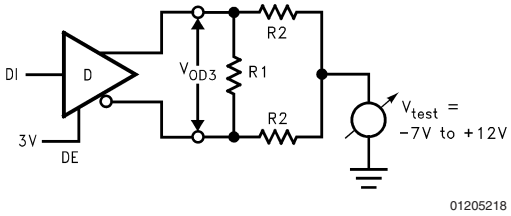


FIGURE 2. Driver V_{OD3}

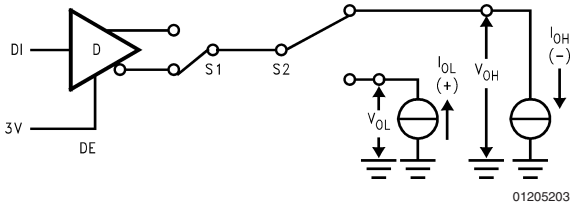
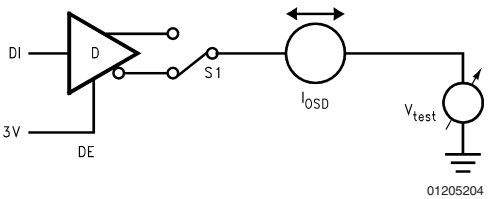


FIGURE 3. Driver V_{OH} and V_{OL}



Vtest = −7V to +12V

FIGURE 4. Driver I_{OSD}

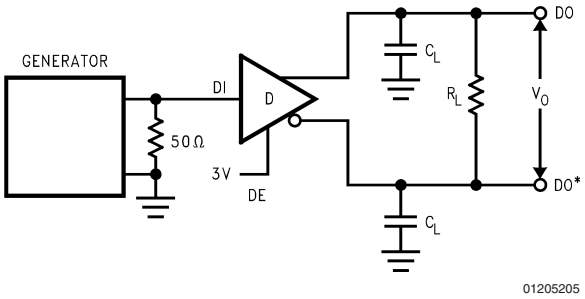


FIGURE 5. Driver Differential Propagation Delay Test Circuit

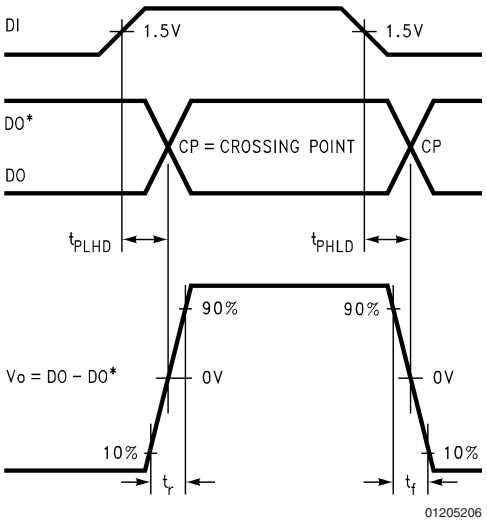


FIGURE 6. Driver Differential Propagation Delays and Differential Rise and Fall Times

Parameter Measurement Information (Continued)

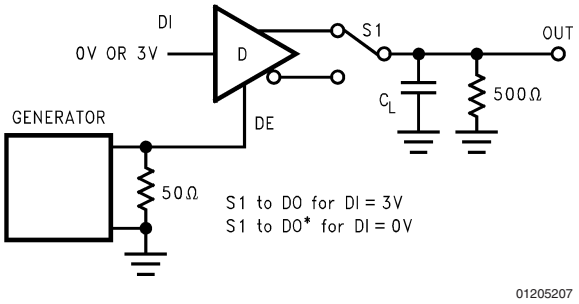


FIGURE 7. TRI-STATE Test Circuit (t_{PZH} , t_{PHZ})

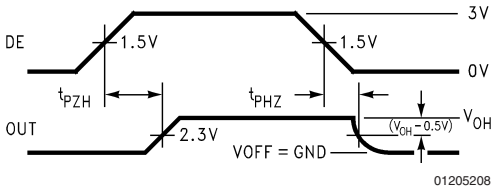


FIGURE 8. TRI-STATE Waveforms (t_{PZH}, t_{PHZ})

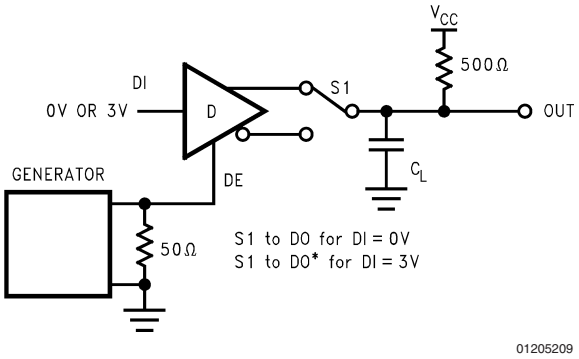


FIGURE 9. TRI-STATE Test Circuit (t_{PZL}, t_{PLZ})

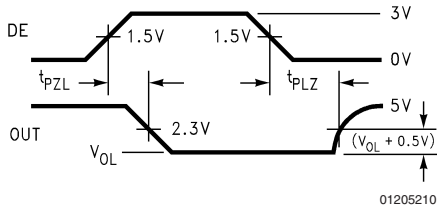


FIGURE 10. TRI-STATE Waveforms (t_{PZL}, t_{PLZ})

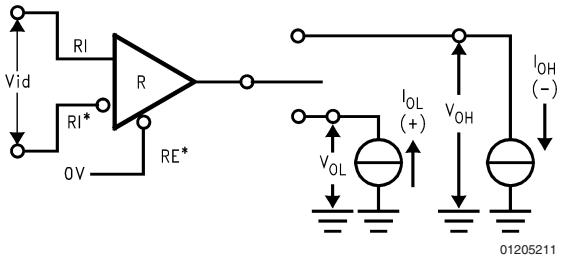


FIGURE 11. Receiver V_{OH} and V_{OL}

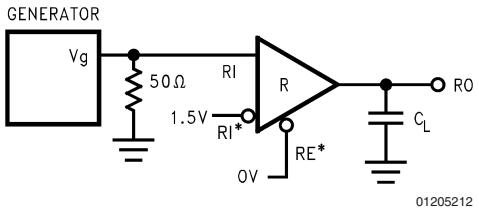


FIGURE 12. Receiver Differential Propagation Delay Test Circuit

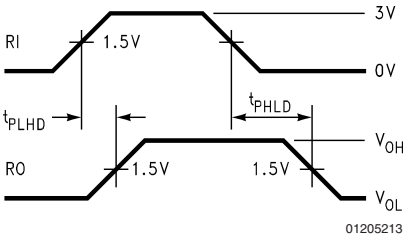


FIGURE 13. Receiver Differential Propagation Delay Waveforms

Parameter Measurement Information (Continued)

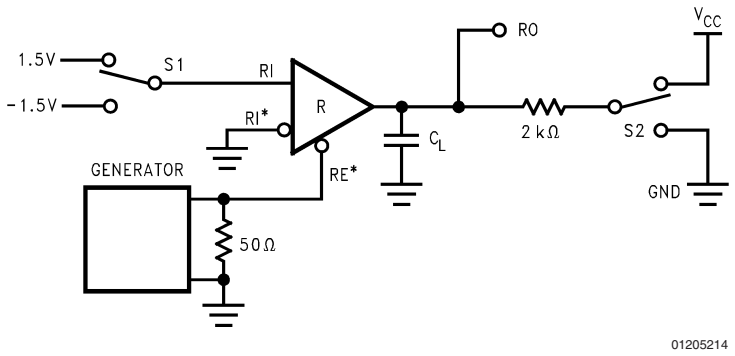


FIGURE 14. Receiver TRI-STATE Test Circuit

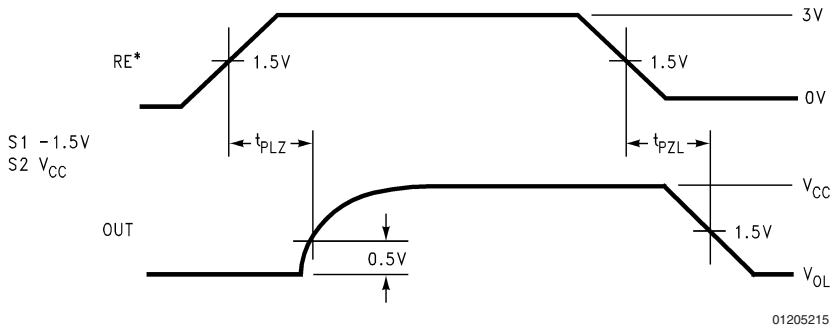


FIGURE 15. Receiver Enable and Disable Waveforms (t_{PLZ}, t_{PZL})

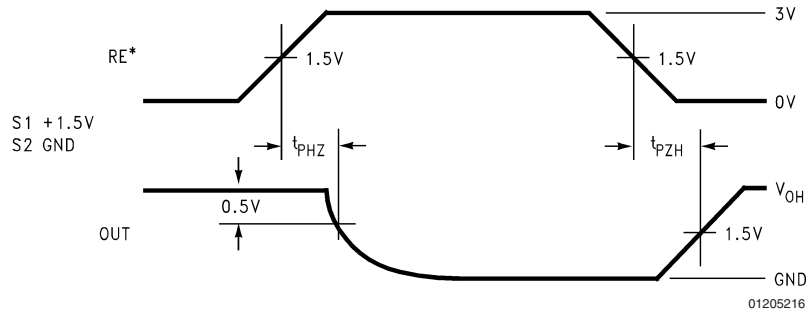


FIGURE 16. Receiver Enable and Disable Waveforms (t_{PHZ}, t_{PZH})

Typical Application Information

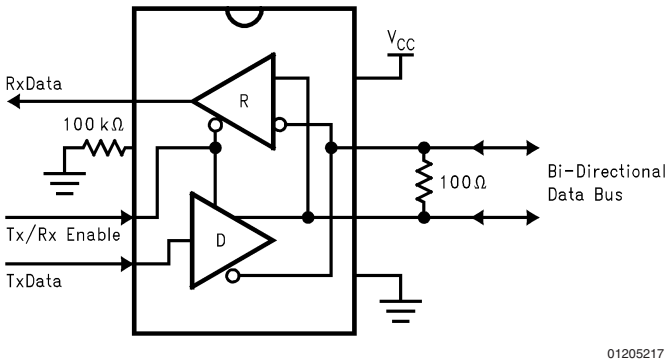


FIGURE 17. Typical Pin Connection

TABLE 1. Device Pin Descriptions

Pin #	Name	Description
1	RO	Receiver Output: When DE/RE* (Receiver Enable) is LOW, the receiver is enabled (ON), if DO/RI ≥ DO*/RI* by 200 mV, RO will be HIGH. If DO/RI ≤ DO*/RI* by 200 mV, RO will be LOW. Additionally RO will be HIGH for OPEN (Non-terminated) inputs.
2	SR	Slew Rate Control: A resistor connected to Ground controls the Driver Output rising and falling edge rates.
3	DE/RE*	Combined Driver and Receiver Output Enable: When signal is LOW the receiver output is enabled and the driver outputs are in TRI-STATE (OFF). When signal is HIGH, the receiver output is in TRI-STATE (OFF) and the driver outputs are enabled.
4	DI	Driver Input: When DE/RE* is HIGH, the driver is enabled, if DI is LOW, then DO/RI will be LOW and DO*/RI* will be HIGH. If DI is HIGH, then DO/RI is HIGH and DO*/RI* is LOW.
5	GND	Ground Connection
6	DO/RI	Driver Output/Receiver Input, 485 Bus Pin.
7	DO*/RI*	Driver Output/Receiver Input, 485 Bus Pin.
8	V_{CC}	Positive Power Supply Connection: Recommended operating range for V_{CC} is +4.75V to +5.25V.

Unit Load

A unit load for a RS-485 receiver is defined by the input current versus the input voltage curve. The gray shaded region is the defined operating range from –7V to +12V. The top border extending from –3V at 0 mA to +12V at +1 mA is defined as one unit load. Likewise, the bottom border extending from +5V at 0 mA to –7V at –0.8 mA is also defined as one unit load (see *Figure 18*). A RS-485 driver is capable of driving up to 32 unit loads. This allows upto 32 nodes on a single bus. Although sufficient for many applications, it is sometime desirable to have even more nodes. For example an aircraft that has 32 rows with 4 seats per row could benefit from having 128 nodes on one bus. This would allow signals to be transferred to and from each individual seat to 1 main station. Usually there is one or two less seats in the last row of the aircraft near the restrooms and food storage area. This frees the node for the main station.

The DS36C278, the DS36C279, and the DS36C280 all have ½ unit load and ¼ unit load (UL) options available. These devices will allow upto 64 nodes or 128 nodes guaranteed over temperature depending upon which option is selected. The ½ UL option is available in industrial temperature and the ¼ UL is available in commercial temperature.

First, for a ½ UL device the top and bottom borders shown in *Figure 18* are scaled. Both 0 mA reference points at +5V and –3V stay the same. The other reference points are +12V at +0.5 mA for the top border and –7V at –0.4 mA for the bottom border (see *Figure 18*). Second, for a ¼ UL device the top and bottom borders shown in *Figure 18* are scaled also. Again, both 0 mA reference points at +5V and –3V stay the same. The other reference points are +12V at +0.25 mA for the top border and –7V at –0.2 mA for the bottom border (see *Figure 18*).

The advantage of the ½ UL and ¼ UL devices is the increased number of nodes on one bus. In a single master multi-slave type of application were the number of slaves exceeds 32, the DS36C278/279/280 may save in the cost of extra devices like repeaters, extra media like cable, and/or extra components like resistors.

The DS36C279 and DS36C280 have addition feature which offer more advantages. The DS36C279 has an automatic sleep mode function for power conscious applications. The DS36C280 has a slew rate control for EMI conscious applications. Refer to the sleep mode and slew rate control portion of the application information section in the corresponding datasheet for more information on these features.

Unit Load (Continued)

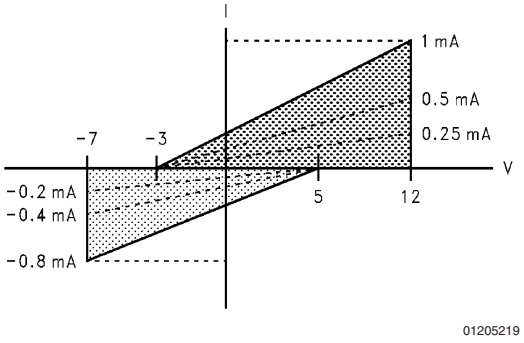


FIGURE 18. Input Current vs Input Voltage Operating Range

Slew Rate Control

The DS36C280 features an adjustable slew rate control. This feature allows more control over EMI levels than traditional fixed edge rate devices. The slew rate control may be adjusted with or without any external components. The DS36C280 offers both low power (I_{CC} 500 µA max) and low EMI for an RS-485 interface.

The slew rate control is located at pin two of the device and only controls the driver output edges. The slew rate control pin (SR) may be left open or shorted to ground, with or without a resistor. When the SR pin is shorted to ground without a resistor, the driver output edges will transition typically 350 ns. When the SR pin is left open, the driver output edges will transition typically 3 µs. When the SR pin is shorted to ground with a resistor, the driver output edges will transition between 350 ns and 3 µs depending on the resistor value. Refer to the slew rate versus resistor value curve in this datasheet for determining resistor values and expected typical slew rate value. Please note, when slowing the edge rates of the device (see *Figure 19*) will decrease the maximum data rate also.

Differential Rise/Fall Time vs Slew Rate Resistor

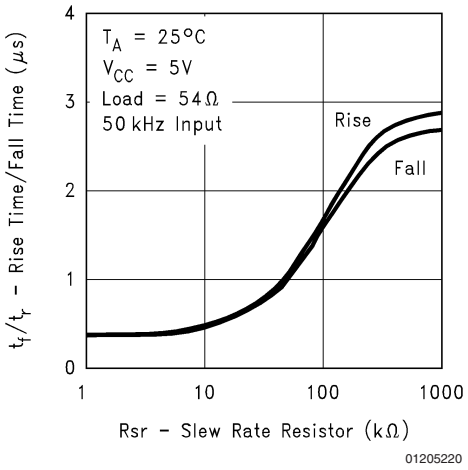
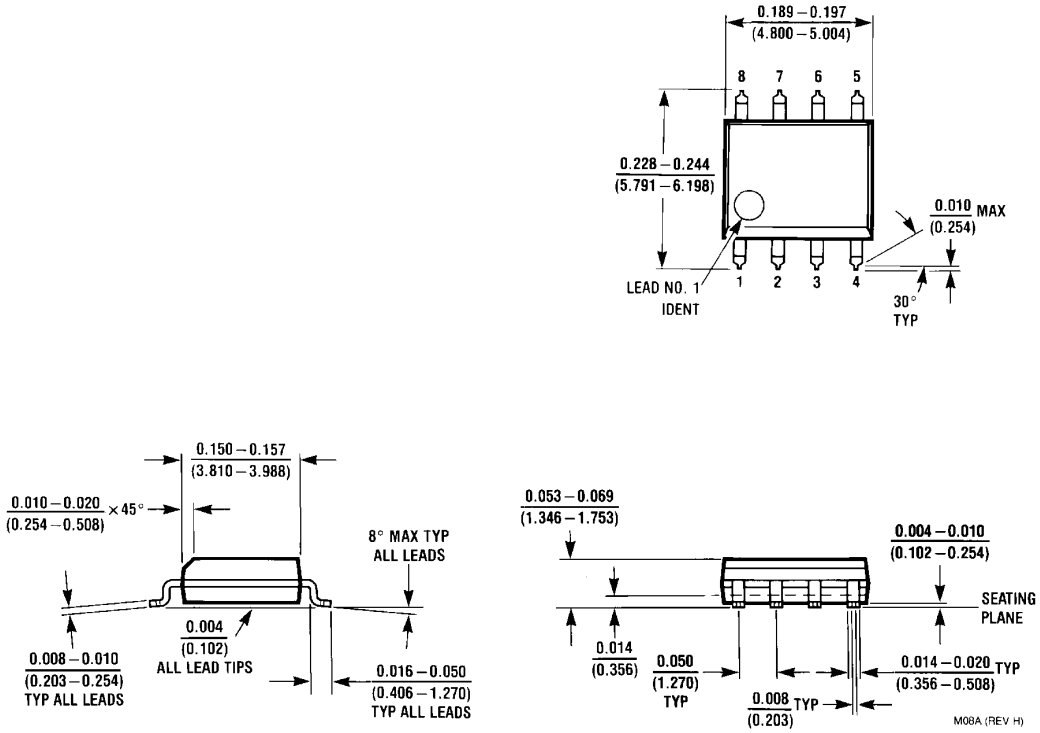


FIGURE 19. Slew Rate Resistor vs Rise/Fall Time

Physical Dimensions inches (millimeters) unless otherwise noted



8-Lead (0.150" Wide) Molded Small Outline Package, JEDEC
Order Number DS36C280M or DS36C280TM
NS Package Number M08A

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